Supporting Information

Fabrication of CuInS₂ Films from Electrodeposited Cu/In Bilayers: Effects of Preheat Treatment on Their Structural, Photoelectrochemical and Solar Cell Properties

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Figure S1. Top-view SEM images of Cu/In bilayers after 110 °C treatment for (a) 10 min and (b) 60 min.
Figure S2. XRD patterns of 520 °C-heated films obtained from (a) the as-deposited Cu/In bilayer and the Cu/In bilayer after 110 °C treatment for (b) 10 min and (c) 60 min.

Figure S3. Current density vs potential scans of CuInS$_2$ films obtained from (a) the as-deposited Cu/In bilayer and the Cu/In bilayer after 110 °C treatment for (b) 10 min and (c) 60 min in 50 mmol dm$^{-3}$ Eu(NO$_3$)$_3$ solution (pH 4) under chopped illumination from a Xe lamp.